P-Channel 72 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A) ^a	Q _g (Typ.)			
70	5.5 at V _{GS} = - 10 V	- 120	149 pC			
- 72	8.5 at V _{GS} = - 4.5 V	- 105	140 110			

FEATURES

- DT-Trench Power MOSFET
- 100 % UIS Tested

APPLICATIONS

· Load Switch



DTK120P07





Top View

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)							
PARAMETER		SYMBOL	LIMIT	UNIT			
Drain-Source Voltage		V _{DS}	-72	V			
Gate-Source Voltage	V _{GS}	± 20	v				
Continuous Drain Current ^d	T _C = 25 °C		-120				
(T _J = 175 °C)	T _C = 125 °C	١D	-105	^			
Pulsed Drain Current	Drain Current		-280	A			
Avalanche Current		I _{AS}	-117				
Single Pulse Avalanche Energy ^a		E _{AS}	286	mJ			
Power Dissinction	T _C = 25 °C °		378	\A/			
Power Dissipation	T _A = 25 °C ^b	гD	4.97	vv			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C			

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	TYPICAL	UNIT		
Junction-to-Ambient	PCB mount ^b	R _{thJA}	45	°C 44		
Junction-to-Case		R _{thJC}	0.55	0/10		

Notes

a. Duty cycle \leq 1 %.

b. When mounted on 1" square PCB (FR4 material).

c. See SOA curve for voltage derating.



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SEMICONDUCTOR





SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 72			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T$	L = - 250 µA		68		m\//ºC	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	η 200 μΑ		- 5.2		mv/ C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1.5		- 3.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
	I _{DSS}	$V_{DS} = -72 V, V_{GS} = 0 V$			- 1		
Zero Gate voltage Drain Current		V_{DS} = - 72 V, V_{GS} = 0 V, T_{J} = 55 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 120			А	
		V _{GS} = - 10 V, I _D = - 30 A		5.5	7.8		
Drain-Source On-State Resistance ^a	DS(on)	V _{GS} = - 4.5 V, I _D = - 20 A		8.5	12	mΩ	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 50 A	18			S	
Dynamic ^b							
Input Capacitance	C _{iss}			8650			
Output Capacitance	C _{oss}	$V_{DS} = -25 V$, $V_{GS} = 0 V$, f = 1 MHz		510		pF	
Reverse Transfer Capacitance	C _{rss}			305			
Total Cata Charge	0	$V_{DS} = -36$ V, $V_{GS} = -10$ V, $I_{D} = -30$ A		148	225	225 95 nC	
Iotal Gate Charge	Qg			72	95		
Gate-Source Charge	Q _{gs}	V_{DS} = - 36 V, V_{GS} = - 4.5 V, I_{D} = - 30 A		18			
Gate-Drain Charge	Q _{gd}			23			
Gate Resistance	Rg	f = 1 MHz		5.2		Ω	
Turn-On Delay Time	t _{d(on)}			26			
Rise Time		V_{DD} = - 36 V, R_L = 2 Ω		35		20	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_{\text{D}}\cong$ - 10 A, V_{GEN} = - 10 V, R_{g} = 1 Ω		150		ns	
Fall Time	t _f			76			
Drain-Source Body Diode Characteristics	6			•			
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C			- 120	٨	
Pulse Diode Forward Current ^a	I _{SM}				- 280	^	
Body Diode Voltage	V _{SD}	I _S = - 30 A		- 1	- 1.5	V	
Body Diode Reverse Recovery Time	t _{rr}			98		ns	
Body Diode Reverse Recovery Charge	Q _{rr}	$I_{}$ 50 A di/dt - 100 A/wa T - 25 °C		61		nC	
Reverse Recovery Fall Time	t _a	$F_{F} = -50$ A, u/ul = 100 A/µs, $F_{J} = 25^{\circ}C$		25			
Reverse Recovery Rise Time	t _b]		16			

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



150





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



On-Resistance vs. Junction Temperature









Drain Source Breakdown vs. Junction Temperature



Maximum Avalanche and Drain Current vs. Case Temperature





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



DIM.		INC	HES	MILLIMETERS		
		MIN.	MAX.	MIN.	MAX.	
А		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
•*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
a 1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
E		0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829 1.9		
	е	0.100) BSC	2.54	BSC	
	К	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010) BSC	0.254	BSC	
	Μ	-	0.002	-	0.050	



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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